

TRD136D

High voltage fast-switching NPN power transistor

Preliminary data

Features

- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed
- Integrated antiparallel collector-emitter diode

Applications

- Electronic ballast for fluorescent lighting
- Electronic transformer for halogen lamps

Description

This device is an NPN power transistor manufactured using high voltage multi epitaxial planar technology for high switching speeds. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a satisfactory RBSOA.

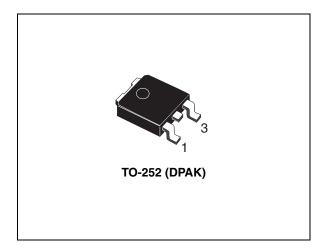


Figure 1. Internal schematic diagram

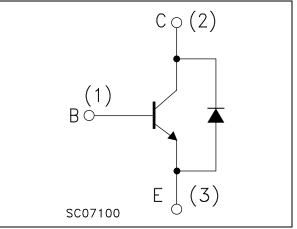


Table 1.Device summary

Part number	Marking	Package	Packaging
TRD136DT4	TRD136D	TO-252	Tape and reel

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Electrical ratings

Tuble 2. Absolute maximum ruting	Table 2.	Absolute	maximum	rating
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Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage ($V_{BE} = 0$)	700	V
V _{CEO}	Collector-emitter voltage $(I_B = 0)$	400	V
V _{EBO}	Emitter-base voltage ($I_{\rm C} = 0$)	9	V
۱ _C	Collector current	3	А
I _{CM}	Collector peak current (t _P < 5ms)	6	А
Ι _Β	Base current	1.5	Α
I _{BM}	Base peak current (t _P < 5ms)	3	Α
P _{tot}	Total dissipation at $T_c \le 25^{\circ}C$	20	W
T _{stg}	Storage temperature -65 to 150		°C
Т _Ј	Max. operating junction temperature	150	°C



2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Symbol	Parameter	Test cond	Min.	Тур.	Max.	Unit	
I _{CEV}	Collector cut-off current (V _{BE} =-1.5V)	V _{CE} = 700 V V _{CE} = 700 V			71	1 5	mA mA
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = 9 V				1	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 10 mA		400			v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_{C} = 0.5 \text{ A}$ $I_{C} = 0.6 \text{ A}$ $I_{C} = 2 \text{ A}$	$I_{B} = 0.1 \text{ A}$ $I_{B} = 60 \text{ mA}$ $I_{B} = 0.5 \text{ A}$			0.5 0.7 1	V V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	$I_{\rm C} = 1 \text{ A}$ $I_{\rm C} = 2 \text{ A}$	I _B = 0.2 A I _B = 0.5 A			1.2 1.6	V V
h _{FE}	DC current gain	$I_{\rm C} = 10 \text{ mA}$ $I_{\rm C} = 2 \text{ A}$	V _{CE} = 5 V V _{CE} = 5 V	10 10		20	
t _s t _f	Inductive load Storage time Fall time	$I_{C} = 1 A$ $V_{BE(off)} = -5 V$ $V_{Clamp} = 200 V$ (see <i>Figure 11</i>)	$R_{BB} = 0 \Omega$		0.8 0.16		µs µs
V _F	Diode forward voltage	I _F = 1 A				2.5	V

Table 3. Electrical characteristics

1. Pulsed duration = 300 ms, duty cycle $\leq 1.5\%$



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2.1 Electrical characteristics (curves)

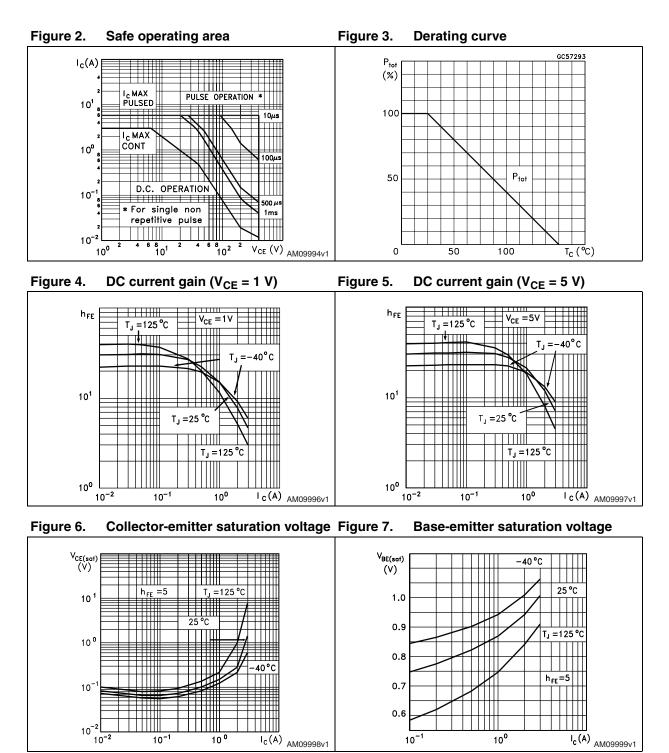


Figure 8. Freewheel diode forward voltage

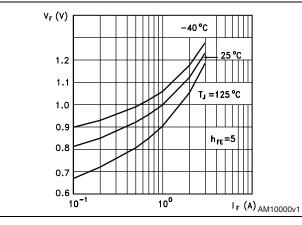


Figure 10. Reverse biased safe operating area

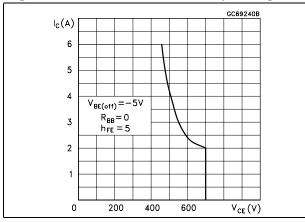
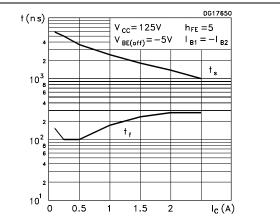


Figure 9. Resistive load switching time





2.2 Test circuits

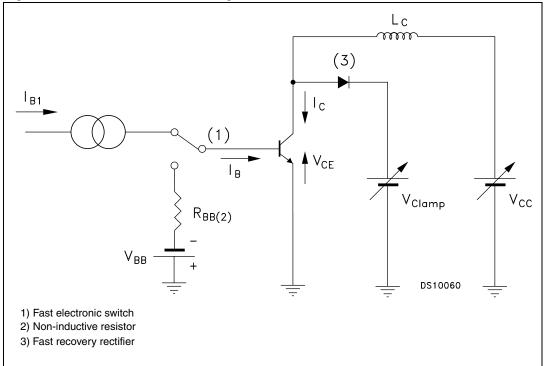


Figure 11. Inductive load switching test circuit



3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



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Dim.		mm	
	Min.	Тур.	Max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
с	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
е		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1		1.50
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0°		8°

 Table 4.
 DPAK (TO-252) mechanical data



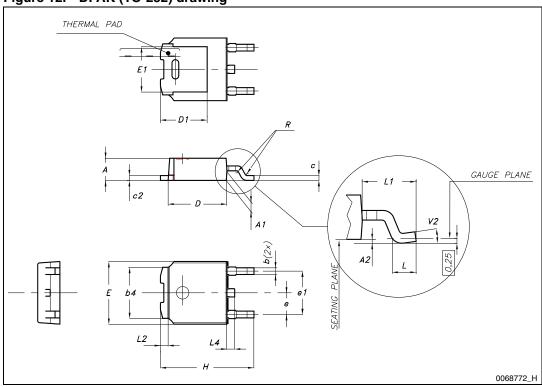


Figure 12. DPAK (TO-252) drawing



4 Revision history

Table 5.Document revision history

Date	Revision	Changes
28-Jun-2011	1	First release



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